

**Amplifier, Power, 2W  
6.5-9.5 GHz**

**MAAP-000064-PKG003**

Rev -  
Advance Information

**Features**

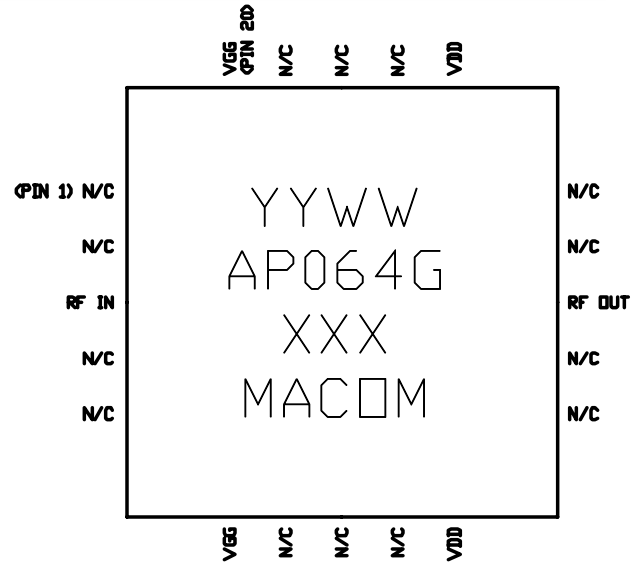
- ◆ **2 Watt Saturated Output Power Level**
- ◆ **Variable Drain Voltage (6-10V) Operation**
- ◆ **MSAG™ Process**

**Description**

The MAAP-000064-PKG003 is a 2-stage 2.0 W power amplifier with on-chip bias networks in a 5mm, 20 lead PQFN package, allowing easy assembly. This product is fully matched to 50 ohms on both the input and output. It can be used as a power amplifier stage or as a driver stage in high power applications.

Each device is 100% RF tested to ensure performance compliance. The part is fabricated using M/A-COM's GaAs Multifunction Self-Aligned Gate (MSAG) Process.

The 5 mm PQFN package has a lead-free lead finish that is RoHS compliant and compatible with a 260°C reflow temperature. The package also features low lead inductance and an excellent thermal path. The MTTF is 1,000,000 hours at 170°C.



**Primary Applications**

- ◆ **Multiple Band Point-to-Point Radio**
- ◆ **SatCom**
- ◆ **ISM Band**

**Also Available in:**

Description	Die	Ceramic Package	Die Sample Board
Part Number	MAAPGM0064-DIE	MAAPGM0064	MAAP-000064-SMB004

**Electrical Characteristics:**  $T_B = 30^\circ C^1$ ,  $Z_0 = 50 \Omega$ ,  $V_{DD} = 8V$ ,  $I_{DQ} = 600mA^2$ ,  $P_{in} = 18 dBm$ ,  $R_G = 120 \Omega$

Parameter	Symbol	Typical	Units
Bandwidth	f	6.5—9.5	GHz
Output Power	$P_{OUT}$	33	dBm
1-dB Compression Point	$P_{1dB}$	32	dBm
Power Added Efficiency	PAE	30	%
Small Signal Gain	G	17	dB
Input VSWR	VSWR	1.8:1	
Output VSWR	VSWR	2.5:1	
Gate Current	$I_{GG}$	< 5	mA
Drain Current	$I_{DD}$	1000	mA
Output Third Order Intercept	TOI	40	dBm

1.  $T_B =$  MMIC Base Temperature
2. Adjust  $V_{GG}$  between -2.4 and -1.3V to achieve specified  $I_{dq}$ .

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### Maximum Ratings<sup>3</sup>

Parameter	Symbol	Absolute Maximum	Units
Input Power	$P_{IN}$	23.0	dBm
Drain Supply Voltage	$V_{DD}$	+12.0	V
Gate Supply Voltage	$V_{GG}$	-3.0	V
Quiescent Drain Current (No RF)	$I_{DQ}$	950	mA
Quiescent DC Power Dissipated (No RF)	$P_{DISS}$	7.9	W
Junction Temperature	$T_J$	170	°C
Storage Temperature	$T_{STG}$	-55 to +150	°C

3. Operation beyond these limits may result in permanent damage to the part.

### Recommended Operating Conditions<sup>4</sup>

Characteristic	Symbol	Min	Typ	Max	Unit
Drain Supply Voltage	$V_{DD}$	6.0	8.0	10.0	V
Gate Supply Voltage	$V_{GG}$	-2.4	-2.0	-1.3	V
Input Power	$P_{IN}$		18.0	21.0	dBm
Thermal Resistance	$\theta_{JC}$		12.4		°C/W
Package Base Temperature	$T_B$			Note 5	°C

4. Operation outside of these ranges may reduce product reliability.

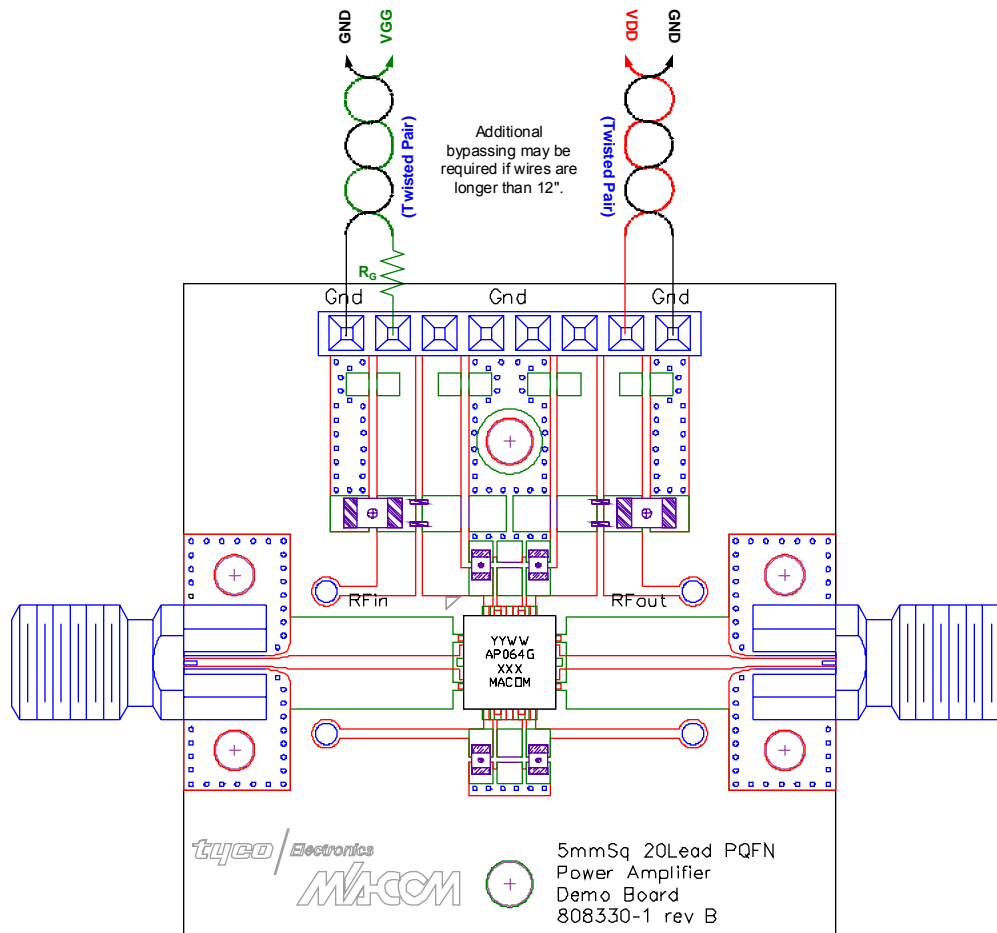
5. MMIC Base Temperature = 170°C —  $\theta_{JC} * V_{DD} * I_{DQ}$

### Operating Instructions

This device is static sensitive. Please handle with care. To operate the device, follow these steps.

1. Apply  $V_{GG} = -2.7$  V,  $V_{DD} = 0$  V.
2. Ramp  $V_{DD}$  to desired voltage, typically 8.0 V.
3. Adjust  $V_{GG}$  to set  $I_{DQ}$ , (approximately @ -2.0 V).
4. Set RF input.
5. Power down sequence in reverse. Turn  $V_{GG}$  off last.





**Figure 3. Demonstration Board PN MAAP-000064-SMB003 (available upon request).**